## NSN 5962-01-420-6435

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Bodv	ı I er	nath:

Between 0.442 inches and 0.460 inches

**Body Width:** 

Between 0.442 inches and 0.460 inches

**Body Height:** 

Between 0.060 inches and 0.100 inches

**Maximum Power Dissipation Rating:** 

1.04 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### **Storage Tempurature Range:**

-65.0/+150.0 degrees celsius

#### **End Application:**

Pacer dawn

#### **Features Provided:**

Bipolar and burn in, mil-std-883, class b and electrostatic sensitive and monolithic and programmed and tested to mil-std-883

#### **Inclosure Material:**

Ceramic

### **Inclosure Configuration:**

Leadless flat pack

## **Output Logic Form:**

Transistor-transistor logic

#### **Input Circuit Pattern:**

14 input

#### **Criticality Code Justification:**

Cbbl

## **Case Outline Source And Designator:**

C-4 mil-m-38510

#### **Current Rating Per Characteristic:**

190.00 milliamperes reverse current, dc absolute

#### **Terminal Surface Treatment:**

Solder

#### **Product Name:**

Microcircuit, programmed (prom 93z665a)

#### Voltage Rating And Type Per Characteristic:

-0.3 volts power source and 7.0 volts power source and 5.5 volts input

#### **Capitance Rating Per Characteristic:**

10.00 input picofarads and 15.00 output picofarads

#### **Time Rating Per Chacteristic:**

100.00 nanoseconds propagation delay and 100.00 nanoseconds access

## Memory Device Type:

Prom

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#### **Special Features:**

Altered item programmed using 14933 82009023a (which is 81349 m38510/21202b3a) using programming instruction 7816354p122

#### **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

**Terminal Type And Quantity:** 

28 leadless

Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

No

Fiig:

A458a0